

#### STTH4R02

#### Ultrafast recovery diode

#### **Features**

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature

#### **Description**

The STTH4R02 uses ST's new 200 V planar Pt doping technology, and it is specially suited for switching mode base drive and transistor circuits.

Packaged in TO-220AC, TO-220FPAC, DPAK, SMB, SMC, and DO-201AB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection.

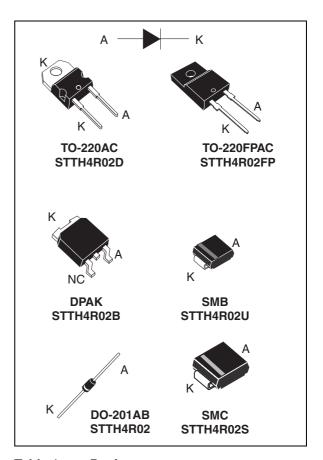


Table 1. Device summary

I <sub>F(AV)</sub>	4 A
$V_{RRM}$	200 V
T <sub>j (max)</sub>	175 °C
V <sub>F</sub> (typ)	0.76 V
t <sub>rr</sub> (typ)	16 ns

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## 1 Characteristics

Table 2. Absolute ratings (limiting values at  $T_{amb} = 25$  °C, unless otherwise stated)

Symbol	Par	Value	Unit		
$V_{RRM}$	Repetitive peak reverse voltage	Repetitive peak reverse voltage			٧
		TO-220AC			
		DPAK		1	
I <sub>F(RMS)</sub>	Forward rms current	SMB / SMC		70	Α
		TO-220FPAC		1	
		DO-201AB		1	
		TO-220AC	T <sub>c</sub> = 160 °C		
		DPAK	T <sub>c</sub> = 160 °C	4	
	Average forward current,	SMB	T <sub>lead</sub> = 95 °C		Α
I <sub>F(AV)</sub>	$\delta = 0.5$	SMC	T <sub>lead</sub> = 95 °C		А
		TO-220FPAC	T <sub>c</sub> = 150 °C	1	
		DO-201AB	T <sub>lead</sub> = 95 °C		
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinu	soidal	70	Α
T <sub>stg</sub>	Storage temperature range			-65 to + 175	°C
Tj	Maximum operating junction te	mperature		175	°C

Table 3. Thermal parameters

Symbol	Parameter	Parameter		
В	Junction to case	TO-220AC / DPAK	3.5	
R <sub>th(j-c)</sub>	Junction to case	TO-220FPAC	6.5	
		SMB	20	°C/W
R <sub>th(j-l)</sub>	R <sub>th(j-l)</sub> Junction to lead	DO-201AB	20	
		SMC	20	

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Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>			3	μA
'R`	Theverse leakage current	T <sub>j</sub> = 125 °C	VR - VRRM		2	20	μΛ
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 12 A		1.15	1.25	
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 4 A		0.95	1.05	V
			1F = 4 A		0.76	0.83	

- 1. Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2 %
- 2. Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2 %

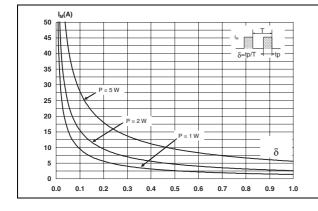
To evaluate the conduction losses use the following equation: P = 0.67 x  $I_{F(AV)}$  + 0.04  $I_{F}^{2}_{(RMS)}$ 

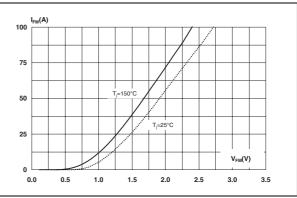
**Dynamic characteristics** Table 5.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>rr</sub>	Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		24	30	ns
rr	Theverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,} \ V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		16	20	113
I <sub>RM</sub>	Reverse recovery current	$I_F = 4 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 160 \text{ V}, T_j = 125 ^{\circ}\text{C}$		4.4	5.5	Α
t <sub>fr</sub>	Forward recovery time	$I_F = 4$ A, $dI_F/dt = 50$ A/ $\mu$ s $V_{FR} = 1.1$ x $V_{Fmax}$ , $T_j = 25$ °C		80		ns
V <sub>FP</sub>	Forward recovery voltage	$I_F = 4 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s},$ $T_j = 25 \text{ °C}$		1.6		V

Figure 1. Peak current versus duty cycle

Figure 2. Forward voltage drop versus forward current (typical values)





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Figure 3. Forward voltage drop versus forward current (maximum values)

Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

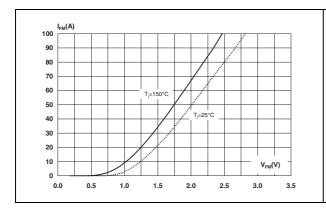
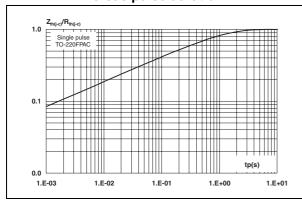


Figure 5. Relative variation of thermal impedance, junction to case, versus pulse duration

Figure 6. Relative variation of thermal impedance, junction to ambient, versus pulse duration (SMB)



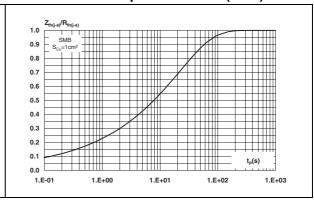
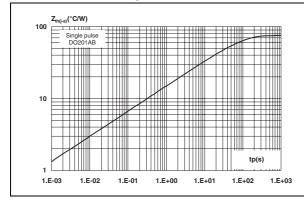
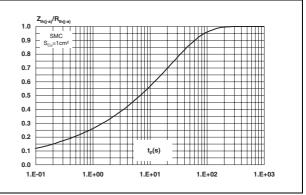


Figure 7. Relative variation of thermal impedance, junction to ambient, versus pulse duration

Figure 8. Relative variation of thermal impedance, junction to ambient, versus pulse duration (SMC)

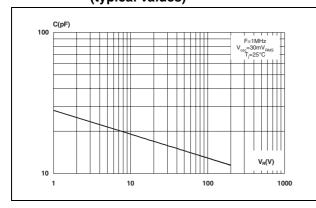




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Figure 9. Junction capacitance versus reverse applied voltage (typical values)

Figure 10. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values)



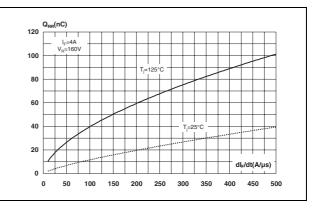
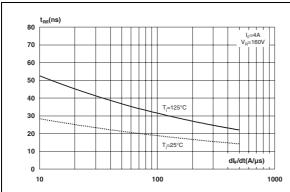


Figure 11. Reverse recovery time versus dl<sub>F</sub>/dt Figure 12. Peak reverse recovery current (typical values)



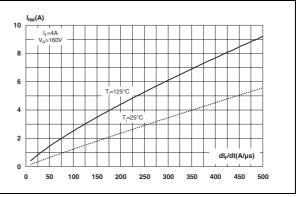
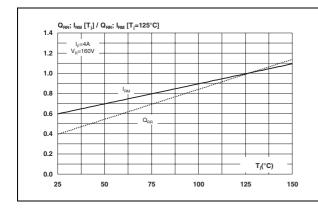


Figure 13. Dynamic parameters versus junction temperature

Figure 14. Thermal resistance, junction to ambient, versus copper surface under tab - DPAK



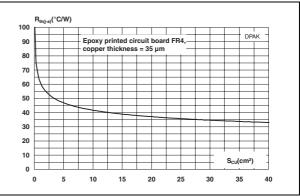
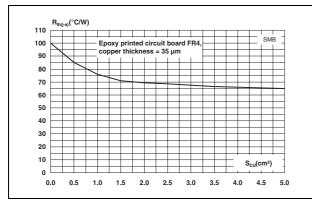


Figure 15. Thermal resistance, junction to ambient, versus copper surface under tab - SMB

Figure 16. Thermal resistance, junction to ambient, versus copper surface under tab - SMC



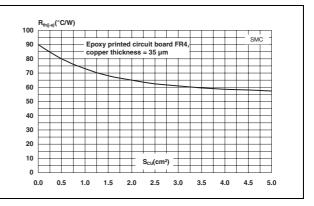
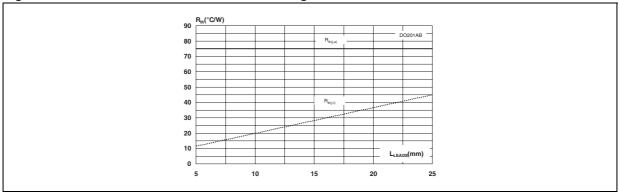
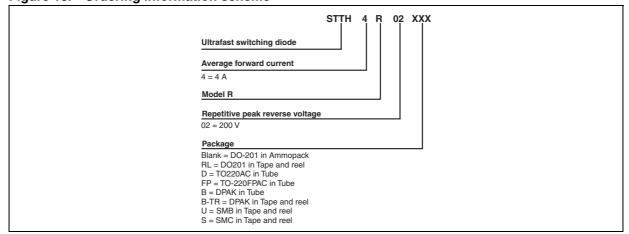


Figure 17. Thermal resistance versus lead length - DO-201AB



### 2 Ordering information scheme

Figure 18. Ordering information scheme



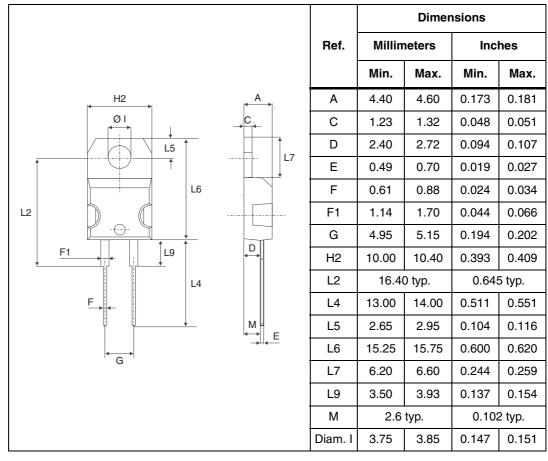
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#### 3 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N⋅m

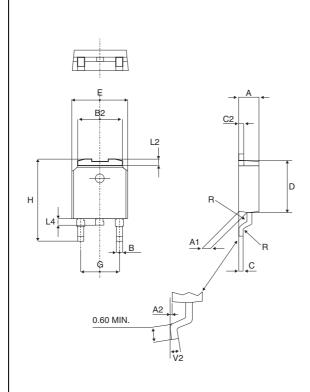
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. T0-220AC dimensions



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Table 7. DPAK dimensions



	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

Figure 19. DPAK footprint

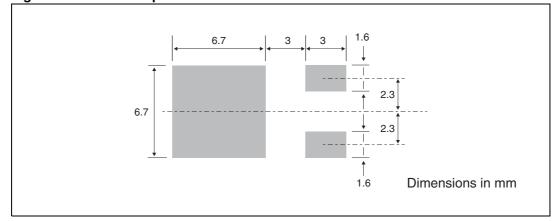
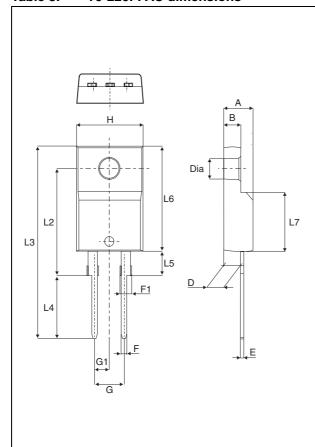


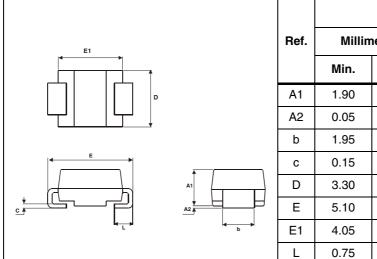
Table 8. T0-220FPAC dimensions



	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
Α	4.4	4.6	0.173	0.181	
В	2.5	2.7	0.098	0.106	
D	2.5	2.75	0.098	0.108	
Е	0.45	0.70	0.018	0.027	
F	0.75	1	0.030	0.039	
F1	1.15	1.70	0.045	0.067	
G	4.95	5.20	0.195	0.205	
G1	2.4	2.7	0.094	0.106	
Н	10	10.4	0.393	0.409	
L2	16	Тур.	0.63 Typ.		
L3	28.6	30.6	1.126	1.205	
L4	9.8	10.6	0.386	0.417	
L5	2.9	3.6	0.114	0.142	
L6	15.9	16.4	0.626	0.646	
L7	9.00	9.30	0.354	0.366	
Dia.	3.00	3.20	0.118	0.126	

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Table 9. SMB dimensions



	Dimensions				
Ref.	Millim	Millimeters		hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.096	
A2	0.05	0.20	0.002	0.008	
b	1.95	2.20	0.077	0.087	
С	0.15	0.40	0.006	0.016	
D	3.30	3.95	0.130	0.156	
Е	5.10	5.60	0.201	0.220	
E1	4.05	4.60	0.159	0.181	
L	0.75	1.50	0.030	0.059	

Figure 20. Footprint, dimensions in mm (inches)

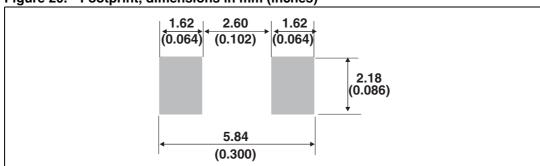


Table 10. SMC dimensions

				Dimer	sions	
	Re		Millim	eters	Inc	hes
E1			Min.	Max.	Min.	Max.
		A1	1.90	2.45	0.075	0.096
D		A2	0.05	0.20	0.002	0.008
		b <sup>(1)</sup>	2.90	3.20	0.114	0.126
E →		c <sup>(1)</sup>	0.15	0.40	0.006	0.016
	<u>† /                                   </u>	D	5.55	6.25	0.218	0.246
	A1	Е	7.75	8.15	0.305	0.321
C E2 L	A2 <sup>†</sup> b	E1	6.60	7.15	0.260	0.281
		E2	4.40	4.70	0.173	0.185
		L	0.75	1.50	0.030	0.059

<sup>1.</sup> Dimensions b and c apply to plated leads

Figure 21. Footprint, dimensions in mm (inches)

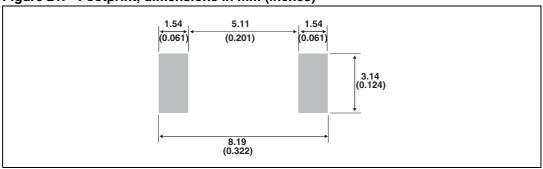
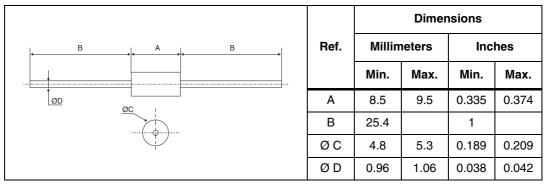


Table 11. DO-201AB dimensions



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## 4 Ordering information

Table 12. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH4R02D	STTH4R02	TO-220AC	1.86 g	50	Tube
STTH4R02FP	STTH4R02	TO-220FPAC	2.2 g	50	Tube
STTH4R02B	STTH4R02	DPAK	0.30 g	75	Tube
STTH4R02B-TR	STTH4R02	DPAK	0.30 g	2500	Tape and reel
STTH4R02U	4R2U	SMB	0.107 g	2500	Tape and reel
STTH4R02	STTH4R02	DO-201AB	0.876 g	600	Ammopack
STTH4R02RL	STTH4R02	DO-201AB	0.876 g	1900	Tape and reel
STTH4R02S	4R2S	SMC	0.243 g	2500	Tape and reel

# 5 Revision history

Table 13. Document revision history

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Date	Revision	Changes		
03-May-2006	1	First issue.		
10-Oct-2006	2	Added SMC package		
13-Apr-2010	3	Updated ECOPACK statement. Updated dimensions tables for SMB and SMC.		
01-Jul-2010	4	Separated junction to lead values from junction to case values in <i>Table 3</i> .		

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